# High Frequency Resistor Programmable Universal Active Filfer Preliminary Dafa Sheet 

## Description

The high frequency resistor programmable universal active filter is a CMOS chip that can be configured for Lowpass, Bandpass, Highpass, Elliptic, Notch or Allpass filters using external resistors. The filters come in one ( 8 pin ) or two (16 pin) section versions. The device is a switched-capacitor filter using a topology that requires fewer pins, less power consumption and provides higher frequency performance than other switched-capacitor universal active filters. The clock to corner ratio as well as the Q are set by external resistors.

Depending on the filter type and response, from zero to nine external resistors are needed for each section. The sections may be cascaded to realize higher order filters.

The devices have a selectable nominal sample to corner ratio of either 6.25 to 1 or 12.5 to 1 and come in either a low power version (for 100 kHz ) or a higher power version (for 500 kHz ). The devices are double sampled to reduce the clock frequency by a factor of two.

## Feafures

Low Power Consumption
High Frequency Operation
Low Cost
Small Package Size
Wide O Range
Wide Clock to Center/Corner Frequency
Range
Ren DIP or SOIC
Accurate Switched-Capacitor
Technology

## Applications

General Purpose Filtering
Portable Equipment
Instrumentation

## Absolufe Maximum Ratings

$\qquad$

| Power Supply Voltage | +6 v |
| :--- | ---: | ---: |
| Storage Temperature | -60 to $+150^{\circ} \mathrm{C}$ |
| Operating Temperature | 0 to $70^{\circ} \mathrm{C}$ |

## Ordering Information

$\qquad$

| Part Number | Package | Operating Temperature |
| :--- | :--- | :---: |
| MSU1HF1P | 8 Pin Dip | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF1S | 8 Pin SOIC | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF2P | 8 Pin Dip | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF2S | 8 Pin SOIC | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF3P | 8 Pin Dip | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF3S | 8 Pin SOIC | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF4P | 8 Pin Dip | $0-70^{\circ} \mathrm{C}$ |
| MSU1HF4S | 8 Pin SOIC | $0-70^{\circ} \mathrm{C}$ |
| MSU2HF1P | 16 Pin Dip | $0-70^{\circ} \mathrm{C}$ |
| MSU2HF1S | 16 Pin SOIC | $0-70^{\circ} \mathrm{C}$ |

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## Electrical Characteristics

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$\left.\begin{array}{|l|c|l|l|l|}\hline \text { PARAMETERS } & \text { SYMBOL } & \text { CONDITIONS } & \text { MIN TYP MAX } & \text { UNITS } \\ \hline \text { DC Specifications } & & & & \\ \hline \text { Operating Voltage } & \text { VDD } & & 4.5 & 5.0 \quad 5.5 \\ \hline \text { Supply Current } & \text { IDD } & \text { MSU2HF1 PWR }=1 \\ \text { MSU2HF1 PWR }=0 \\ \text { MSU1HF1/3 } \\ \text { MSU1HF2/4 }\end{array}\right)$
note(1): the clock to corner ratio is one-half the sample to corner ratio
note(2): 100 mV sine wave clock requires capacitive coupling

## Block Diagram

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*BPP input is noninverting

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| Pin Description |  |  |  |
| :---: | :---: | :---: | :---: |
| 16 Pin | 8 Pin |  |  |
| 1 |  | PWR | Power Select Pin $0=$ High $1=$ Low |
| 2 | 8 | VSS | Negative Supply, Typically 0V for single supply, - 2.5 V for dual supply |
| 3 | 1 | OUT1 | Section One Output |
| 4 | 5 | GND | Ground Reference, Typically 2.5V for single supply, OV for dual supply |
| 5 | 2 | LP1 | Section One Lowpass Input |
| 6 | 3 | BPN1 | Section One Negative Bandpass Input |
| 7 |  | BPP1 | Section One Positive Bandpass Input |
| 8 | 4 | HP1 | Section One High Pass Input |
| 9 |  | HP2 | Section Two High Pass Input |
| 10 |  | BPP2 | Section Two Positive Bandpass Input |
| 11 |  | BPN2 | Section Two Negative Bandpass Input |
| 12 |  | LP2 | Section Two Lowpass Input |
| 13 | 6 | CLK | Input Clock, Typically 200 mV for AC coupled sine wave, 5 V for CMOS input |
| 14 |  | OUT2 | Section Two Output |
| 15 |  | FO | Clock to Center/Corner, Select Pin, Low $=6.25$ to 1 High $=3.125$ (sample rate is 2 x ) |
| 16 | 7 | VDD | Positive Supply, Typically 5V for single supply, 2.5V for dual supply |

Pin Configuration $\qquad$


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| Filter Types Available |  |  | Block D | Diagram |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MSU2HF1 | MSU1HF1/4 |  |  |  |  |
| Lowpass | yes | yes |  |  |  |  |
| Bandpass | yes | yes | LP | - $\Sigma$ |  | $\Sigma$ |
| Highpass | yes | yes |  |  |  |  |
| Lowpass elliptical | yes | yes |  |  |  |  |
| Highpass elliptical | 1 yes | yes |  |  |  |  |
| Notch | yes | yes |  |  |  |  |
| Oscillator | yes | no |  |  |  |  |
| Allpass | yes | no |  |  |  |  |
| Biquad | yes | no |  | BP+ | BP- | HP |

Programming Non-Linearities $\qquad$ Transfer Functions $\qquad$


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## Lowpass

$H(s)=-\frac{\omega_{0}^{2}}{S^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}{ }^{2}}$

## Bandpass

$H(s)=\frac{-\left(\omega_{0} / Q\right) S}{s^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}^{2}}$

## Highpass

$$
H(s)=\frac{S^{2}}{s^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}^{2}}
$$

## Lowpass Elliptic

$$
H(s)=\frac{\left(\omega_{0} / \omega_{z}\right)^{2} S^{2}+\omega_{0}^{2}}{s^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}^{2}}
$$

## Highpass Elliptic

$$
H(s)=\frac{s^{2}+\left(\omega_{z} / \omega_{0}\right)^{2} \omega_{0}^{2}}{s^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}^{2}}
$$

Notch
$H(s)=\frac{s^{2}+\omega_{0}^{2}}{s^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}^{2}}$
Allpass
$H(s)=\frac{S^{2}-\left(\omega_{0} / Q\right) S+\omega_{0}{ }^{2}}{S^{2}+\left(\omega_{0} / Q\right) S+\omega_{0}{ }^{2}}$

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NOTE:<br>

For lowpass, lowpass elliptical, highpass elliptical, allpass and notch filters. This limitation due to the particular ratio of $R_{1}$ and $\mathrm{R}_{2}$ and allows realizable values of $R_{3}$. Other minimum values of $\mathrm{fc} / \mathrm{fo}$ can be obtained by using other values of $R_{1}$ and $R_{2}$ in the basic biquad equations.


Assumption (1) $R_{1}=R_{2} ; D C$ Gain $=$ Unity
$f_{0}=\sqrt{K_{1}} \cdot \frac{f c}{\alpha(2)} \quad K_{1}=\frac{R_{3}}{R_{1}+2 R_{3}}$

$$
\mathrm{Q}=\sqrt{\frac{K_{1}}{K_{2}}} \quad \mathrm{~K}_{2}=\frac{R_{6}}{R_{4}+R_{6}}
$$

(1) If a gain other than unity is desired then gain $=R_{1} / R_{2}$ and $K_{1}$ from the biquad equations should be substituted for $\mathrm{K}_{1}$
(2) where $\alpha$ is 6.25 or 12.5 .


Gain $\quad(1)=\frac{1}{K_{2}}$
$\mathrm{f}_{\mathrm{O}}=\sqrt{\mathrm{K}_{1}} \cdot \frac{\mathrm{fc}}{\overline{\alpha(2)}}$
$K_{1}=\frac{R_{3}}{R_{1}+R_{3}}$
$\mathrm{Q}=\frac{\sqrt{\mathrm{K}_{1}}}{\mathrm{~K}_{2}}$
$\mathrm{K}_{2}=\frac{\mathrm{R}_{6}}{\mathrm{R}_{4}+\mathrm{R}_{6}}$
(1) Gain may be adjusted independent of O using the resistor divider described by $\mathrm{K}_{5}$ from the biquad equations. Use the $\mathrm{K}_{5}$ equation in place of $\mathrm{K}_{2}$ for the gain equation only.
(2) where $\alpha$ is 6.25 or 12.5 .


Assumption(1) $\mathrm{R}_{4}=\mathrm{R}_{5}$; Gain $=$ Unity
$\mathrm{f}_{\mathrm{O}}=\sqrt{\mathrm{K}_{1}} \cdot \frac{\mathrm{fc}}{\alpha(2)} \mathrm{K}_{1}=\frac{\mathrm{R}_{3}}{\mathrm{R}_{1}+\mathrm{R}_{3}}$
$\mathrm{Q}=\frac{\sqrt{\mathrm{K}_{1}}}{\mathrm{~K}_{2}} \quad \mathrm{~K}_{2}=\frac{\mathrm{R}_{6}}{\mathrm{R}_{4}+2 \mathrm{R}_{6}}$
(1) For gains not equal to unity, gain $=$
$R_{4} / R_{5}$ and $K_{2}$ should be replaced with
$\mathrm{K}_{2}$ from the biquad equations.
(2) where $\alpha$ is 6.25 or 12.5 .

Gain = Unity
$f_{0}=\sqrt{K_{1}} \cdot \frac{f c}{\alpha(1)} \quad K_{1}=\frac{R_{3}}{R_{1}+R_{3}}$
$0=\frac{\sqrt{K_{1}}}{K_{2}}$
$K_{2}=\frac{R_{6}}{R_{4}+R_{6}}$

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Gain $=$ Unity; $R_{1}=R_{2}$
$\mathrm{f}_{0}=\sqrt{\mathrm{K}_{1}} \cdot \frac{\mathrm{fc}}{\alpha} \quad \mathrm{K}_{1}=\frac{\mathrm{R}_{3}}{\mathrm{R}_{1}+2 \mathrm{R}_{3}}$

$$
\mathrm{Q}=\frac{\sqrt{K_{1}}}{\mathrm{~K}_{2}} \quad \mathrm{~K}_{2}=\frac{\mathrm{R}_{6}}{\mathrm{R}_{4}+\mathrm{R}_{6}}
$$

(1) where $\alpha$ is 6.25 or 12.5 .


The biquad is the most general purpose filter type. By adjusting the values of K1 through K6, virtually any second order transfer function can be achieved. In some cases, it may be necessary to use an inverting op amp to achieve the correct polarity on these constants.

$$
\begin{gathered}
\text { VOUT }=\frac{\operatorname{VIN}\left[-K_{3} \mathrm{~S}_{2}-\mathrm{K}_{4} \mathrm{~S} \frac{\mathrm{fc}}{4}+\mathrm{K}_{5} \mathrm{~S} \frac{\mathrm{fc}}{4}-\mathrm{K}_{6} \frac{\mathrm{fc}^{2}}{16}\right]}{\mathrm{S}_{2} \frac{\mathrm{~K}_{2} \mathrm{~S} \frac{\mathrm{fc}}{4}+\mathrm{K}_{1} \frac{\mathrm{Fc}^{2}}{16}}{}} . \frac{}{\frac{16}{4}}
\end{gathered}
$$



